

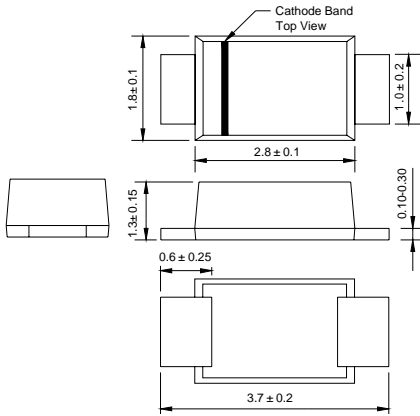


# SODF1 THRU SODF7

## SURFACE MOUNT FAST RECOVERY RECTIFIER

Reverse Voltage - 50 to 1000 Volts Forward Current - 0.7 Ampere

### SOD-123FL



### FEATURES

- ◆ Glass passivated device
- ◆ Ideal for surface mounted applications
- ◆ Low reverse leakage
- ◆ Metallurgically bonded construction
- ◆ High temperature soldering guaranteed:  
250°C/10 seconds, 0.375" (9.5mm) lead length,  
5 lbs. (2.3kg) tension

### MECHANICAL DATA

**Case:** JEDEC SOD-123FL molded plastic body over passivated chip  
**Terminals:** Solderable per MIL-STD-750, Method 2026  
**Polarity:** Color band denotes cathode end  
**Mounting Position:** Any  
**Weight:** 0.0007 ounce, 0.02 grams

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

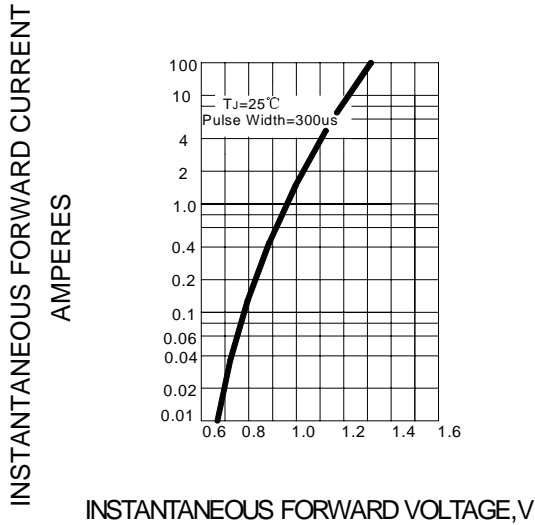
Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

MDD Catalog Number	SYMBOLS	SODF1	SODF2	SODF3	SODF4	SODF5	SODF6	SODF7	UNITS
		F1	F2	F3	F4	F5	F6	F7	
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	VOLTS
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	VOLTS
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	VOLTS
Maximum average forward rectified current at $T_A=65^\circ\text{C}$ (NOTE 1)	$I_{(AV)}$	0.7							Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) $T_L=25^\circ\text{C}$	$I_{FSM}$	25.0							Amps
Maximum instantaneous forward voltage at 0.7A	$V_F$	1.15							Volts
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=125^\circ\text{C}$	$I_R$	10.0 50.0							$\mu\text{A}$
Maximum reverse recovery time (NOTE 2)	$t_{rr}$	150				250	500		ns
Typical junction capacitance (NOTE 3)	$C_J$	4							pF
Typical thermal resistance (NOTE 4)	$R_{\theta JA}$	180							K/W
Operating junction and storage temperature range	$T_{J, T_{STG}}$	-50 to +150							$^\circ\text{C}$

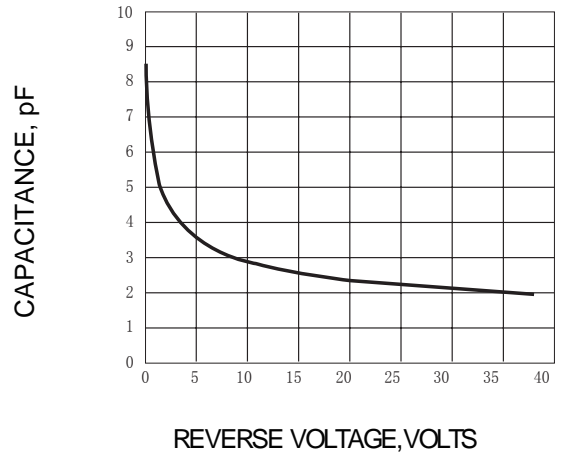
- Note:**
1. Averaged over any 20ms period.
  2. Measured with  $I_F=0.5\text{A}$ ,  $I_R=1\text{A}$ ,  $I_{rr}=0.25\text{A}$ .
  3. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
  4. Thermal resistance junction to ambient, 6.0 mm<sup>2</sup> copper pads to each terminal.

# RATINGS AND CHARACTERISTIC CURVES SODF1 THRU SODF7

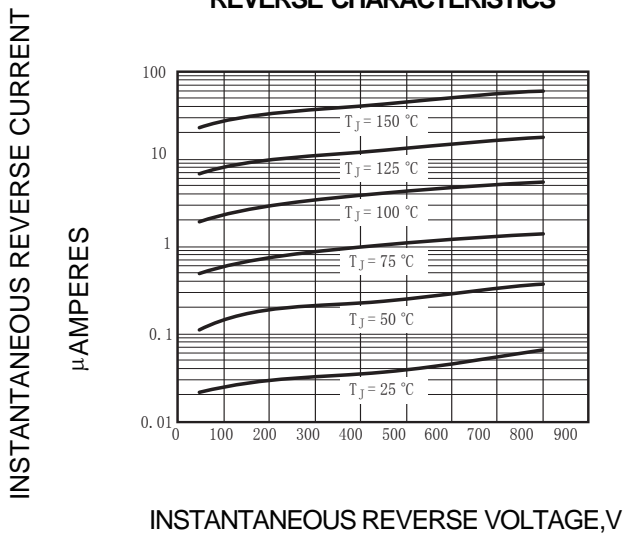
**FIG.1 – TYPICAL FORWARD CHARACTERISTIC**



**FIG.2 – TYPICAL JUNCTION CAPACITANCE**



**FIG.3 – TYPICAL INSTANTANEOUS REVERSE CHARACTERISTICS**



**FIG.4 – FORWARD DERATING CURVE**

